

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

application of

Takashi KOBAYASHI et al.

Serial No.: 10/020,573

Group Art Unit:2826

Filed: October 31, 2001

Examiner: Greene, P.

For:

SEMICONDUCTOR DEVICE

Certificate of Mailing

I hereby certify that this paper is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria VA 22313-1450 on:

Marc A. Rossi

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450, Alexandria, VA 22313-1450

Sir:

Pursuant to 37 C.F.R. §1.56, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached Form PTO-1449. Each item of information contained in the Information Disclosure Statement was first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the Information Disclosure Statement. Copies of the references listed on Form PTO-1449 and relevant portions of the search report are attached.

It is respectfully requested that the information be expressly considered during the prosecution of this application, that these references be made of record therein and appear among the "References Cited" on any patent to issue therefrom, and that an initialed copy of the PTO-1449 be returned to the undersigned.

Respectfully submitted,

Marc A. Rossi

Registration No. 31,923

Date: 05/67/63

Attorney Docket No.: FUJI:200

ROSSI & ASSOCIATES P.O. Box 826 Ashburn, VA 20146-0826 (703) 726-6020

	INFO				CITATION	· .	Docket Number (Option FUJI: 200 Applicant(s)			Application Number 10/020,5		
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Form PTO-A820 (also form PTO-1449)

not considered. Include copy of this form with next communication to applicant.

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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and

Patent and Trademark Office * U.S. DEPARTMENT OF COMMERC







Application No: Claims searched:

GB 0125466.3

26 to 28

Examiner: Date of search:

T P Marlow 26 March 2003

Patents Act 1977: Further Search Report under Section 17

Documents considered to be relevant:

Category	Relevant to claims	Identity of document ar	nd passage or figure of particular relevance
X	26-28	EP 0115093 A2	PHILIPS - see breakdown voltage sustaining layer (12) above highly doped n or p-type layer (13), (see page 7 line 6 and page 7 line 27), and guard rings (1 to 6) surrounding well region (11) in Fig. 1; page 12 lines 12 to 16 mention breakdown voltage of less than 550 V for six guard rings
X	26-28	US 5028548	PHILIPS - see breakdown voltage sustaining layer (12) and guard rings (14) above layer (15); col. 4 line 56 to col. 6 line 25 give devices with breakdown voltages of 500V for six guard rings
A		GB 2161649 A	TOSHIBA - see p ⁺ guard rings (14) surrounding p ⁺ well region (24) in n ⁻ layer (12) above p ⁺ layer (10) in Fig. 1
A		EP 0671769 A2	NIPPONDENSO - see guard rings (5) surrounding well region (3,9) above p ⁺ layer (10) and breakdown voltage sustaining layer (11) in Fig. 1
A		US 5510634	NIPPONDENSO - see guard rings (6) surrounding well region (7) above p ⁺ layer (4) and breakdown voltage sustaining layer (3) in Fig. 1

Categories:

X Document indicating lack of novelty or inventive step
Y Document indicating lack of inventive step if combined with one or more other documents of same category.
& Member of the same patent family
E Patent document published on or after, but with priority date earlier than, the filing date of this application.

Field of Search:

Search of GB, EP, WO & US patent documents classified in the following areas of the UKC^v.







Application No: Claims searched:

GB 0125466.3

26 to 28

Examiner:

T P Marlow

Date of search:

26 March 2003

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Worldwide search of patent documents classified in the following areas of the IPC7:

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The following online and other databases have been used in the preparation of this search report:

WPI, EPODOC, JAPIO